

# ZXTN19100CFF

## 100V, SOT23F, NPN high gain power transistor

### Summary

$BV_{CEX} > 200V$

$BV_{CEO} > 100V$

$BV_{ECO} > 5V$

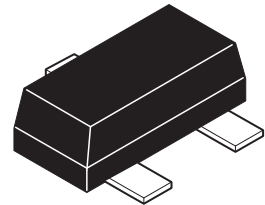
$I_{C(cont)} = 4.5A$

$V_{CE(sat)} < 60mV @ 1A$

$R_{CE(sat)} = 38m\Omega$

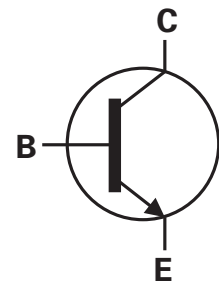
$P_D = 1.5W$

Complementary part number ZXTP19100CFF



### Description

Advanced process capability has been used to maximise the performance of this transistor. The SOT23F package is compatible with the industry standard SOT23 footprint but offers lower profile and higher dissipation for applications where power density is of utmost importance

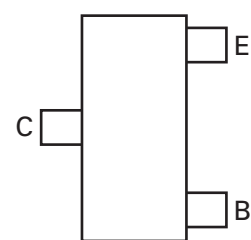


### Features

- High forward blocking voltage
- Low saturation voltage
- High gain
- Low profile high dissipation package

### Applications

- Relay and solenoid driving
- DC fans
- Industrial and automotive switching



Pinout - top view

### Ordering information

Device	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN19100CFFTA	7	8	3000

### Device marking

1E5

# ZXTN19100CFF

## Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Collector-base voltage	$V_{CBO}$	200	V
Collector-emitter voltage (forward blocking)	$V_{CEX}$	200	V
Collector-emitter voltage	$V_{CEO}$	100	V
Emitter-collector voltage (reverse blocking)	$V_{ECO}$	5	V
Emitter-base voltage	$V_{EBO}$	7	V
Continuous collector current <sup>(c)</sup>	$I_C$	4.5	A
Base current	$I_B$	1	A
Peak pulse current	$I_{CM}$	6	A
Power dissipation at $T_{amb} = 25^{\circ}C^{(a)}$		0.84	
Linear derating factor	$P_D$	6.72	W
Power dissipation at $T_{amb} = 25^{\circ}C^{(b)}$		1.34	mW/°C
Linear derating factor	$P_D$	10.72	W
Power dissipation at $T_{amb} = 25^{\circ}C^{(c)}$		1.5	mW/°C
Linear derating factor	$P_D$	12.0	W
Power dissipation at $T_{amb} = 25^{\circ}C^{(d)}$		2	mW/°C
Linear derating factor	$P_D$	16.0	W
Operating and storage temperature range	$T_j, T_{stg}$	- 55 to 150	°C

## Thermal resistance

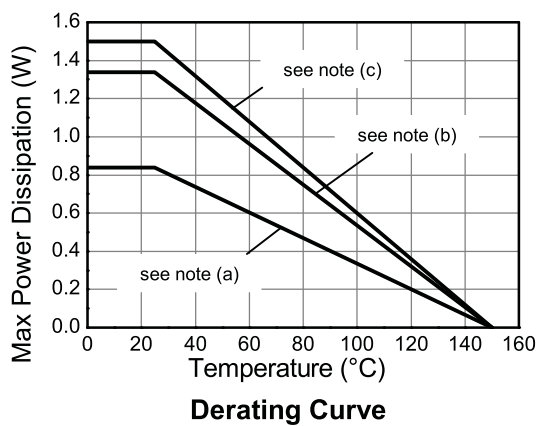
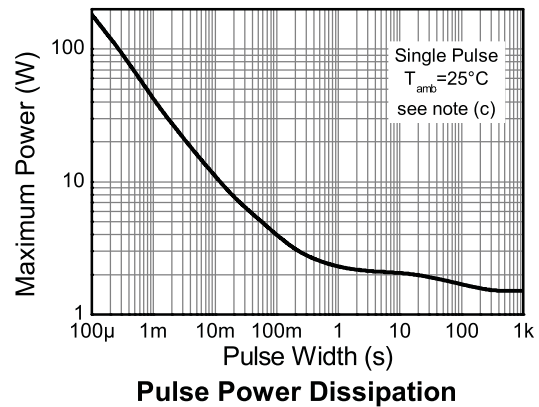
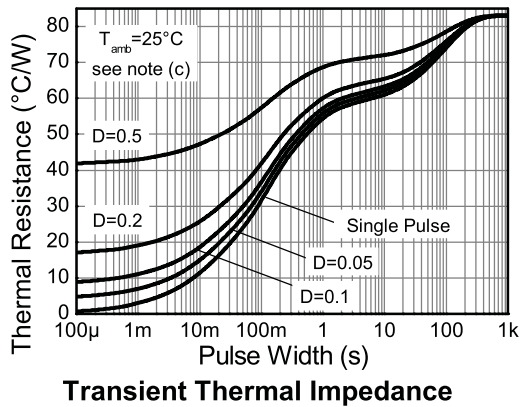
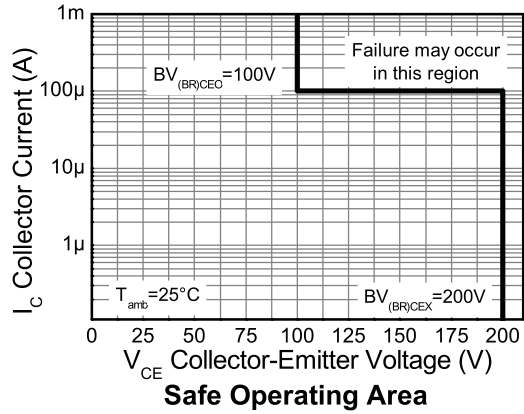
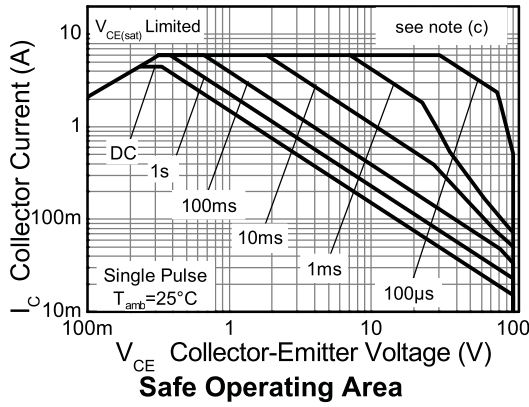
Parameter	Symbol	Limit	Unit
Junction to ambient <sup>(a)</sup>	$R_{\theta JA}$	149.3	°C/W
Junction to ambient <sup>(b)</sup>	$R_{\theta JA}$	93.4	°C/W
Junction to ambient <sup>(c)</sup>	$R_{\theta JA}$	83.3	°C/W
Junction to ambient <sup>(d)</sup>	$R_{\theta JA}$	60	°C/W

### NOTES:

- (a) For a device surface mounted on 15mm x 15mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- (b) Mounted on 25mm x 25mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.
- (c) Mounted on 50mm x 50mm x 1.6mm FR4 PCB with a high coverage of single sided 2 oz copper in still air conditions.
- (d) As (c) above measured at t<5secs.

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## Characteristics



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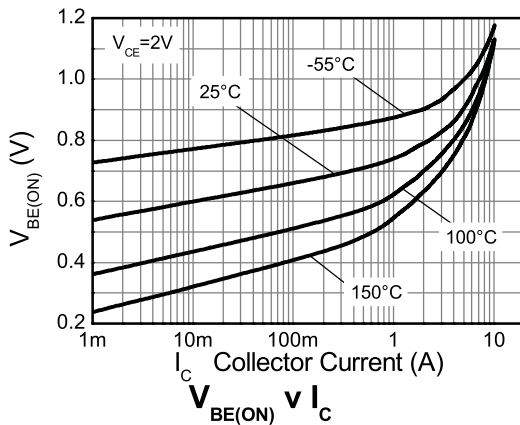
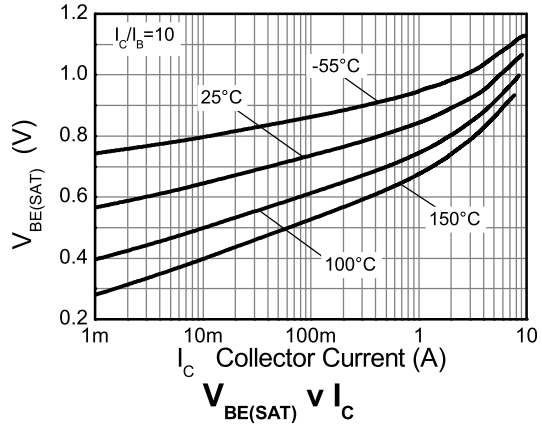
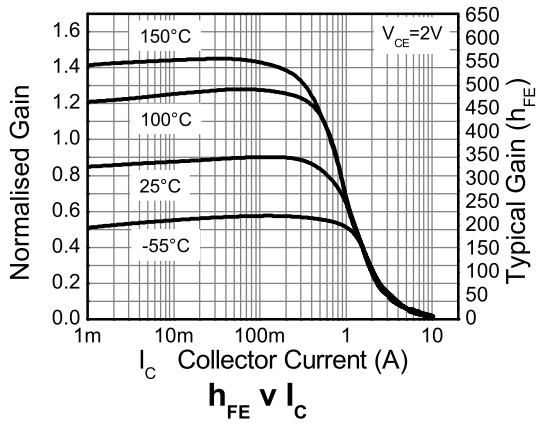
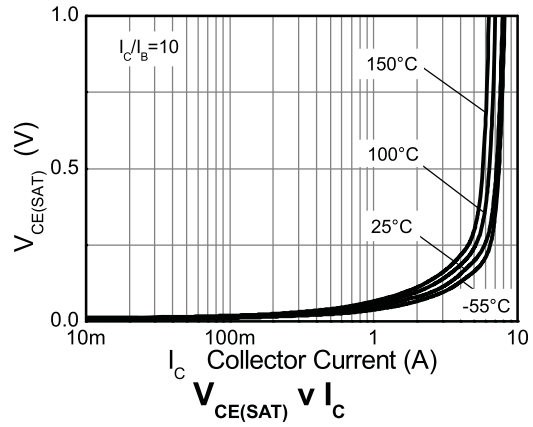
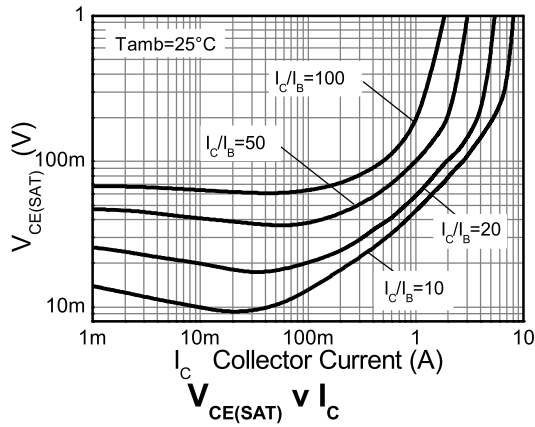
## Electrical characteristics (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CBO}$	200	240		V	$I_C = 100\mu\text{A}$
Collector-emitter breakdown voltage (forward blocking)	$BV_{CEX}$	200	240		V	$I_C = 100\mu\text{A}$ , $R_{BE} < 1\text{k}\Omega$ or $-1\text{V} < V_{BE} < 0.25\text{V}$
Collector-emitter breakdown voltage (base open)	$BV_{CEO}$	100	120		V	$I_C = 10\text{mA}^{(*)}$
Emitter-base breakdown voltage	$BV_{EBO}$	7	8.3		V	$I_E = 100\mu\text{A}$
Emitter-collector breakdown voltage (reverse blocking)	$BV_{ECX}$	6	8.3		V	$I_E = 100\mu\text{A}$ , $R_{BC} < 1\text{k}\Omega$ or $0.25\text{V} > V_{BC} > -0.25\text{V}$
Emitter-collector breakdown voltage (base open)	$BV_{ECO}$	5	8		V	$I_E = 100\mu\text{A}$ ,
Collector-base cut-off current	$I_{CBO}$		<1	50 20	nA $\mu\text{A}$	$V_{CB} = 160\text{V}$ $V_{CB} = 160\text{V}$ , $T_{amb} = 100^{\circ}\text{C}$
Collector-emitter cut-off current	$I_{CEX}$		<1	100	nA	$V_{CE} = 160\text{V}$ , $R_{BE} < 1\text{k}\Omega$ or $-1\text{V} < V_{BE} < 0.25\text{V}$
Emitter-base cut-off current	$I_{EBO}$		<1	50	nA	$V_{EB} = 5.6\text{V}$
Collector-emitter saturation voltage	$V_{CE(sat)}$		45 105 170	60 135 235	mV mV mV	$I_C = 1\text{A}$ , $I_B = 100\text{mA}^{(*)}$ $I_C = 1\text{A}$ , $I_B = 20\text{mA}^{(*)}$ $I_C = 4.5\text{A}$ , $I_B = 450\text{mA}^{(*)}$
Base-emitter saturation voltage	$V_{BE(sat)}$		950	1050	mV	$I_C = 4.5\text{A}$ , $I_B = 450\text{mA}^{(*)}$
Base-emitter turn-on voltage	$V_{BE(on)}$		880	1000	mV	$I_C = 4.5\text{A}$ , $V_{CE} = 2\text{V}^{(*)}$
Static forward current transfer ratio	$h_{FE}$	200 130	350 250 25	500		$I_C = 0.1\text{A}$ , $V_{CE} = 2\text{V}^{(*)}$ $I_C = 1\text{A}$ , $V_{CE} = 2\text{V}^{(*)}$ $I_C = 5\text{A}$ , $V_{CE} = 2\text{V}^{(*)}$
Transition frequency	$f_T$		150		MHz	$I_C = 100\text{mA}$ , $V_{CE} = 10\text{V}$ $f = 50\text{MHz}$
Input capacitance	$C_{ibo}$		305		pF	$V_{EB} = 0.5\text{V}$ , $f = 1\text{MHz}^{(*)}$
Output capacitance	$C_{obo}$		15.7	25	pF	$V_{CB} = 10\text{V}$ , $f = 1\text{MHz}^{(*)}$
Delay time	$t_d$		28.3		ns	$V_{CC} = 10\text{V}$ .
Rise time	$t_r$		23.6		ns	$I_C = 500\text{mA}$ ,
Storage time	$t_s$		962		ns	$I_{B1} = I_{B2} = 50\text{mA}$ .
Fall time	$t_f$		133		ns	

### NOTES:

(\*) Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ ; duty cycle  $\leq 2\%$ .

## Typical characteristics

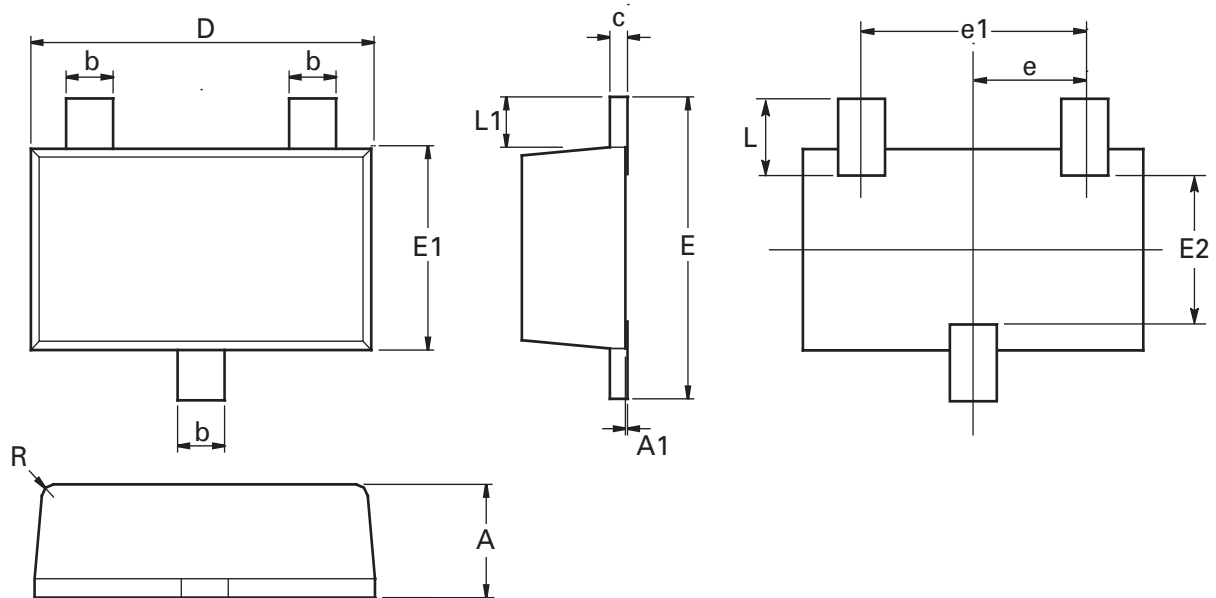


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# ZXTN19100CFF

## Package outline - SOT23F



Dim.	Millimeters		Inches		Dim.	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Max.	Max.
A	0.80	1.00	0.0315	0.0394	E	2.30	2.50	0.0906	0.0984
A1	0.00	0.10	0.00	0.0043	E1	1.50	1.70	0.0590	0.0669
b	0.35	0.45	0.0153	0.0161	E2	1.10	1.26	0.0433	0.0496
c	0.10	0.20	0.0043	0.0079	L	0.48	0.68	0.0189	0.0268
D	2.80	3.00	0.1102	0.1181	L1	0.30	0.50	0.0153	0.0161
e	0.95 ref		0.0374 ref		R	0.05	0.15	0.0019	0.0059
e1	1.80	2.00	0.0709	0.0787	O	0°	12°	0°	12°

**Note:** Controlling dimensions are in millimeters. Approximate dimensions are provided in inches

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Europe	Americas	Asia Pacific	Corporate Headquarters
Zetex GmbH Kustermann-park Balanstraße 59 D-81541 München Germany Telephone: (49) 89 45 49 49 0 Fax: (49) 89 45 49 49 49 europe.sales@zetex.com	Zetex Inc 700 Veterans Memorial Highway Hauppauge, NY 11788 USA Telephone: (1) 631 360 2222 Fax: (1) 631 360 8222 usa.sales@zetex.com	Zetex (Asia Ltd) 3701-04 Metroplaza Tower 1 Hing Fong Road, Kwai Fong Hong Kong Telephone: (852) 26100 611 Fax: (852) 24250 494 asia.sales@zetex.com	Zetex Semiconductors plc Zetex Technology Park, Chadderton Oldham, OL9 9LL United Kingdom Telephone: (44) 161 622 4444 Fax: (44) 161 622 4446 hq@zetex.com

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Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: [ocean@oceanchips.ru](mailto:ocean@oceanchips.ru)

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А